## NSN 5961-01-128-4825

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View Online at https://aerobasegroup.com/nsn/5961-01-128-4825 **Inclosure Material:** Plastic **Overall Length:** 3.620 inches **Overall Height:** 0.787 inches **Overall Width:** 1.417 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 semiconductor device thyristor **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 1300.0 nonrepetitive peak reverse voltage all semiconductor device thyristor and 1200.0 repetitive peak reverse voltage all semiconductor device thyristor and 1200.0 repetitive peak off-state voltage all semiconductor device thyristor **Current Rating Per Characteristic:** 50.00 amperes forward current, total rms torr all semiconductor device thyristor and 25.00 amperes forward current, total rms universal all semiconductor device thyristor and 300.00 amperes peak forward surge current absolute all semiconductor device thyristor **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank all semiconductor device thyristor and 0.5 watts small-signal input power, common-collector universal all semiconductor device thyristor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Test Data Document:** 10110-140195 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 screw Shelf Life: N/a **Unit Of Measure: Demilitarization:**